

DATA SHEET

SEMICONDUCTOR

KBP200~KBP210

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE

GLASS PASSIVATED BRIDGE RECTIFIE

VOLTAGE RANGE-50 to 1000 Volts CURRENT-2.0 Amperes

FEATURES

Ideal for printed circuit board

Surge overload rating: 60 Amperes peak

- High temperature soldering : 260°C / 10 seconds at terminals
- Pb free product at available : 99% Sn above meet RoHS
- environment substance directive request

MECHANICAL DATA

Case:Molded plastic

Epoxy: UL 94V-0 rate flame retardant

Lead: MIL-STD-202E, Method 208 guaranteed

Polarity: Symbols molded or marked on body

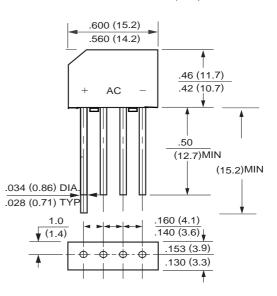
Mounting position: Any

Weight: 2.74 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

KBP Unit:inch(mm)



		SYMBOL	KBP200	KBP201	KBP202	KBP204	KBP206	KBP208	KBP210	UNITS
Maximum Recurrent Peak Reverse Voltage		VRRM	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage		VRMS	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage		VDC	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output TA = 50		10	2.0							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave		IFSM	60							Amps
superimposed on rated load (JEDEC method)										
Maximum Forward Voltage Drop per element at 1.0A DC		VF	1.0							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage per element	@TA = 25	IR	5							µAmp
	@TA = 100	IK	500							
I2t Rating for Fusing(t<8.3ms)		I2t	10							A2Sec
Typical Junction Capacitance(Note1)		CJ	15							pF
Operating Temperature Range		ТJ	-55 to + 150							
Storage Temperature Range		TSTG	-55 to + 150							

NOTES: 1.Measured at 1 MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Ambient and from junction to lead mounted on P.C.B with 0.47x0.47" (12x12mm) copperpads.

DEVICE CHARACTERISTICS

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